

Polar3[™] HiperFET[™] **Power MOSFET**

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

IXFA26N50P3 IXFP26N50P3 IXFQ26N50P3 **IXFH26N50P3**

Maximum Ratings

6.0

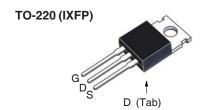
500V **26A** $250m\Omega$

TO-263 (IXFA)

Symbol

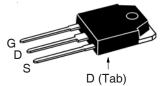


Test Conditions





BP (IXFQ)
BP (IXFQ)



Syllibol	Test Conditions	Maxilliulli n	aunys
V _{DSS}	$T_{J} = 25^{\circ}C \text{ to } 150^{\circ}C$	500	V
V _{DGR}	$T_{_{\rm J}} = 25^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}, R_{_{\rm GS}} = 1\text{M}\Omega$	500	V
V_{gss}	Continuous	± 30	V
V _{GSM}	Transient	± 40	V
I _{D25}	T _c = 25°C	26	Α
I _{DM}	$T_{\rm c} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	78	Α
I _A	T _c = 25°C	13	Α
E _{AS}	$T_{c} = 25^{\circ}C$	300	mJ
dv/dt	$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	35	V/ns
P_{D}	T _C = 25°C	500	W
T _J		-55 +150	°C
T_{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	Plastic Body for 10s	260	°C
F_c	3	65 / 2.214.6	N/lb
M _d	Mounting Torque (TO-220, TO-3P & TO-247)	1.13 / 10	Nm/lb.in
Weight	TO-263	2.5	g
	TO-220 TO-3P	3.0 5.5	g g
	10 01	0.0	9

V _{DGR}	$T_J = 25^{\circ}C$ to 150°C, $R_{GS} = 1M\Omega$	500	V
V _{GSS}	Continuous	± 30	V
V _{GSM}	Transient	± 40	V
I _{D25}	T _C = 25°C	26	A
I _{DM}	$T_{\rm C}$ = 25°C, Pulse Width Limited by $T_{\rm JM}$	78	Α
I _A	T _C = 25°C	13	A
E _{as}	$T_{c} = 25^{\circ}C$	300	mJ
dv/dt	$I_{_{S}} \le I_{_{DM}}, V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} \le 150^{\circ}C$	35	V/ns
P_{D}	T _C = 25°C	500	W
T _J		-55 +150	°C
T _{JM}		150	°C
T _{stg}		-55 +150	°C
T,	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	Plastic Body for 10s	260	°C
F _c	Mounting Force (TO-263) 10.	.65 / 2.214.6	N/lb

TO-247 (IXFH)	
G D S	D (Tab)

G = Gate	D	= Drain
S = Source	Tab	= Drain

Features

- Fast Intrinsic Rectifier
- Avalanche Rated
- $^{\bullet}$ Low $\rm R_{\rm \scriptscriptstyle DS(ON)}$ and $\rm Q_{\rm \scriptscriptstyle G}$
- Low Package Inductance

Advantages

g

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol (T _J = 25°C	Test Conditions Unless Otherwise Specified)	Charac Min.	teristic Typ.	Values Max.	i
BV _{DSS}	$V_{GS} = 0V, I_{D} = 1mA$	500			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 4mA$	3.0		5.0	V
I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_{J} = 125$ °C			25 750	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			250	mΩ

TO-247



Symbol (T _J = 25°C, U	SymbolTest ConditionsCharact $(T_J = 25^{\circ}\text{C}, \text{ Unless Otherwise Specified})$ Min.		cteristic Values Typ. Max		
g_{fs}	V _{DS} = 20V, I _D = 0.5 • I _{D25} , Note 1	14	23	S	
R_{Gi}	Gate Input Resistance		2.1	Ω	
C _{iss}			2220	pF	
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		280	pF	
C _{rss}			8	pF	
	Effective Output Capacitance				
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		108	pF	
C _{o(tr)}	Time related $\int V_{DS}^{dS} = 0.8 \cdot V_{DSS}$		185	pF	
t _{d(on)}	Resistive Switching Times		21	ns	
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		7	ns	
t _{d(off)}	$R_{\rm G} = 3\Omega$ (External)		38	ns	
t,	$n_{\rm G} = 352$ (External)		5	ns	
$Q_{g(on)}$			42	nC	
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		11	nC	
Q_{gd}			15	nC	
R _{thJC}				0.25 °C/W	
R _{thCS}	TO-220		0.50	°C/W	
	TO-3P & TO-247		0.25	°C/W	

Source-Drain Diode

Symbol Test Conditions		Charac	cteristic \	/alues	
$(T_J = 25^{\circ}C, I)$	Unless Otherwise Specified)	Min.	Тур.	Max	
I _s	$V_{GS} = 0V$			26	Α
I _{SM}	Repetitive, pulse Width Limited by $T_{_{\rm JM}}$			104	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
$\left. egin{array}{c} \mathbf{t}_{rr} & \\ \mathbf{Q}_{RM} & \\ \mathbf{I}_{RM} & \end{array} ight. ight.$	$I_F = 13A$, -di/dt = 100A/ μ s $V_R = 100V$		0.9 10.2	250	ns nC A

Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.



Fig. 1. Output Characteristics @ T_J = 25°C

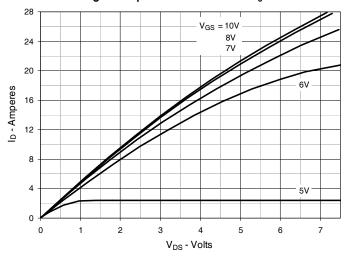


Fig. 2. Extended Output Characteristics @ T_J = 25°C

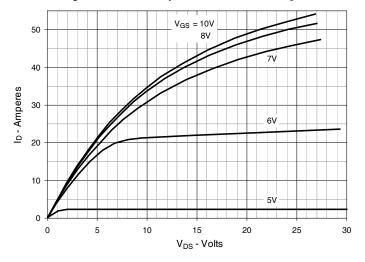


Fig. 3. Output Characteristics @ T_J = 125°C

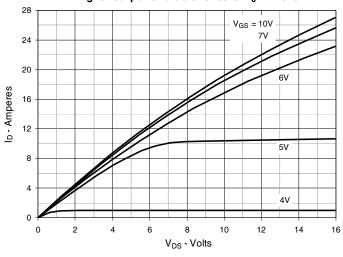


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 13A$ Value vs.

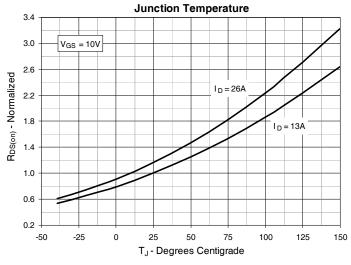


Fig. 5. $R_{DS(on)}\,\text{Normalized to I}_D$ = 13A Value vs.

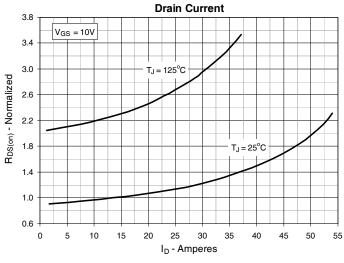
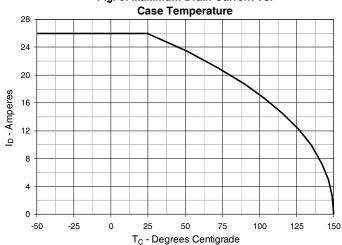
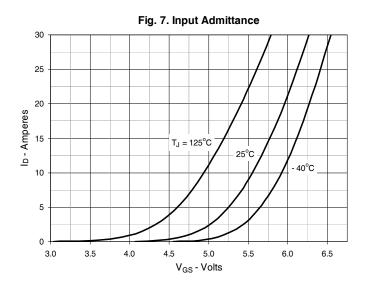
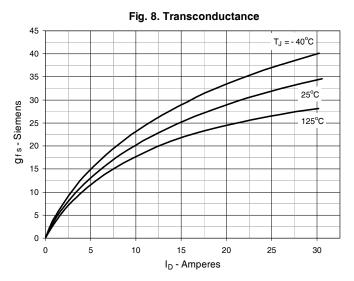


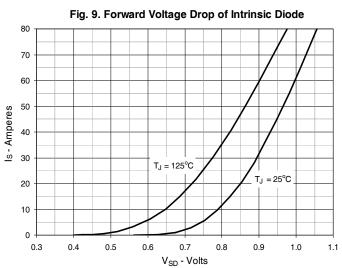
Fig. 6. Maximum Drain Current vs.

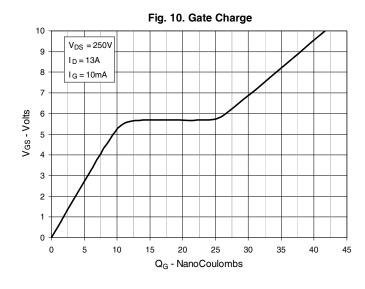


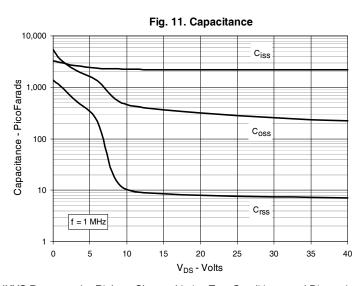


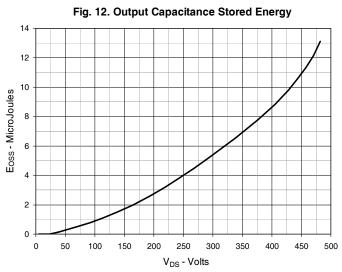












 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.



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Fig. 13. Forward-Bias Safe Operating Area

100

RDS(on) Limit

100

TJ = 150°C

TC = 25°C

Single Pulse

0.1

100

V_{DS} - Volts

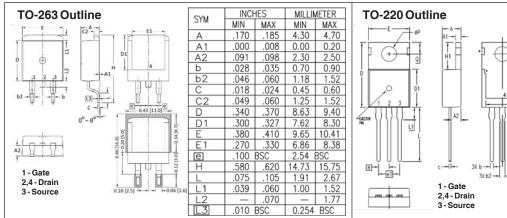
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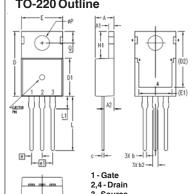
Fig. 14. Maximum Transient Thermal Impedance

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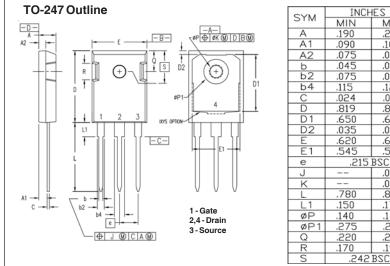


IXFA26N50P3 IXFP26N50P3 IXFQ26N50P3 IXFH26N50P3

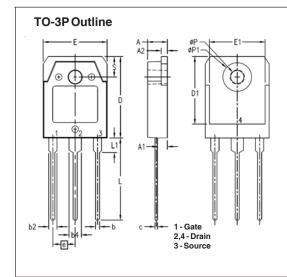




MYZ	INC	HES	MILLIM	ETERS
21M	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
С	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
е	.100 BSC		2.54	BSC
e1	.200	BSC	5.08	BSC
H1	.244	.268	6.20	6.80
Ĺ	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



CVM	YM INCHES MILLI		MILLIN	1ETERS
STIVI			MAX	
Α	.190	.205	4.83	5.21
Α1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
Ь	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
С	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
Ε	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
е	.215	BSC	5.45	BSC
J		.010		0.25
K		.025		0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØΡ	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242BSC 6.15BSC			BSC



SYM	INCHES		MILLIN	METERS
SIM	MIN	MAX	MIN	MAX
Α	.181	.197	4.60	5.00
A1	.087	1.02	2.20	2.60
A2	.057	.065	1.45	1.65
σ	.031	.047	0.80	1.20
b2	.071	.087	1.80	2.20
b4	.110	.126	2.80	3.20
O	.022	.031	0.55	0.80
D	.776	.791	19.70	20.10
D1	.640	.680	16.26	17.27
Ε	.606	.622	15.40	15.80
E1	.531	.539	13.50	13.70
е	.215 BSC		5,45	BSC
Г	.779	.795	19.80	20.20
L1	.130	.146	3.30	3.70
ØΡ	.122	.134	3.10	3.40
øP1	.272	.280	6.90	7.10
S	.189	.205	4.80	5.20

